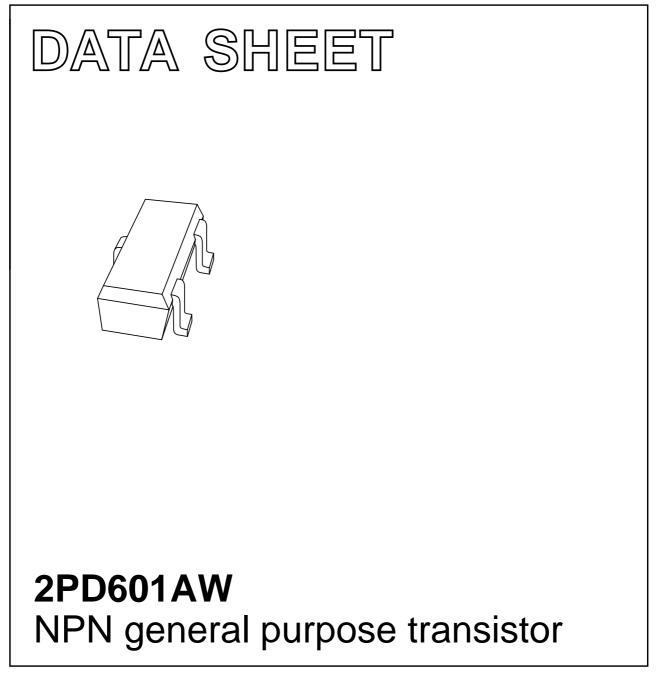
DISCRETE SEMICONDUCTORS



Preliminary specification

2002 Jun 26



FEATURES

- High collector current (max. 100 mA)
- Low collector-emitter saturation voltage (max. 500 mV).

APPLICATIONS

· General purpose switching and amplification.

DESCRIPTION

NPN transistor in an SC-70 (SOT323) plastic package. PNP complement: 2PB709AW.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
2PD601AQW	*6D
2PD601ARW	*6E
2PD601ASW	*6F

Note

- 1. * = -: made in Hong Kong.
 - * = t: made in Malaysia.

Top view MAM062 Simplified outline SC-70 (SOT323) Fig.1

and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	60	V
V _{CEO}	collector-emitter voltage	open base	_	50	V
V _{EBO}	emitter-base voltage	open collector	_	6	V
I _C	collector current (DC)		_	100	mA
I _{CM}	peak collector current		_	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

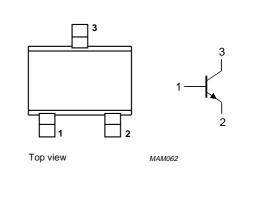
Note

1. For mounting conditions, see "Thermal considerations and footprint design for SOT323 in the General Part of Data Handbook SC18".

2PD601AW

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



2PD601AW

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	625	K/W

Note

1. For mounting conditions, see "Thermal considerations and footprint design for SOT323 in the General Part of Data Handbook SC18".

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	I _E = 0; V _{CB} = 60 V	-	10	nA
		$I_E = 0; V_{CB} = 60 V; T_j = 150 °C$	-	5	μA
I _{EBO}	emitter-base cut-off current	I _C = 0; V _{EB} = 5 V	-	10	nA
h _{FE}	DC current gain	I _C = 100 mA; V _{CE} = 2 V; note 1	90	-	
	DC current gain	I _C = 2 mA; V _{CE} = 10 V			
	2PD601AQW		160	260	
	2PD601ARW		210	340	
	2PD601ASW		290	460	
V _{CEsat}	collector-emitter saturation voltage	I _C = 100 mA; I _B = 10 mA; note 1	-	500	mV
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = 10 V; f = 1 MHz$	-	3.5	pF
f _T	transition frequency	I _C = 2 mA; V _{CE} = 10 V;			
	2PD601AQW	f = 100 MHz	100	-	MHz
	2PD601ARW		120	_	MHz
	2PD601ASW		140	-	MHz

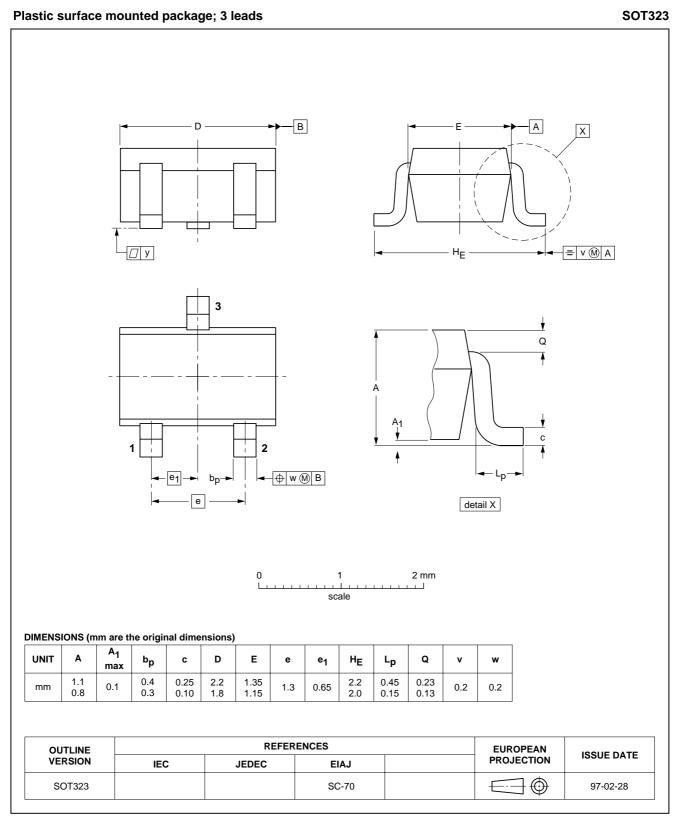
Note

1. Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$

2PD601AW

NPN general purpose transistor

PACKAGE OUTLINE



2PD601AW

DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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2PD601AW

NOTES

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NOTES

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Printed in The Netherlands

613514/01/pp**8**

Date of release: 2002 Jun 26

Document order number: 9397 750 09757

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